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EFFECT OF SOLUTION TEMPERATURE ON VOLTAGE RANGE AND SENSITIVITY OF LOW-TEMPERATURE SENSOR CU/NI RESULTS FROM ELECTROPLATING ASSISTED BY PARALLEL MAGNETIC FIELDS

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ABSTRACT

This study aims to identify the effect of solution temperature aided by parallel magnetic fields on the sensitivity and voltage range of the Cu/Ni sensor as a low-temperature sensor. Solution temperature was varied from 30°C-70°C. The results of data analysis showed that the highest sensitivity is a sensor which is deposited at a temperature of 60°C with a sensitivity level (0.118 ± 0.004) mV/°C with R^2= 0.98 and sensor which has the lowest sensitivity sensor with the deposition temperature of 30°C is (0.0004 ± 0.007) mV/°C with R^2= 0.96. In contrast to the sensitivity, the highest voltage range is 39.67 mV owned by the sensor which is deposited at 30°C and 60°C while the lowest voltage range is 32.04 mV as a result of the deposition temperature of 40°C.

Key words: Sensitivity, voltage range, thin film Cu/Ni, electroplating, parallel magnetic field

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1. INTRODUCTION

The availability of Cryogenic sensors in the 21st century has become a very important requirement. Cryogenic sensors are widely used in various fields, including in the aerospace and nuclear fields [1], livestock field [2], health sector, even in the food industry [3]. Cryogenic sensors that are quite popularly used are thermocouple and temperature detector

(RTD) resistance sensors [4]. Cryogenic temperature is known to be very low, namely -196°C [5]. However, in many measurement cases, errors in the thermocouple sensor often occur because they are unable to measure the assumed temperature. In contrast to the RTD sensors that have high accuracy with excellent output [6-7]. The basic working principle of the RTD sensor is to take advantage of changes in material resistance to temperature changes [8]. The resistance of the material will increase when the temperature increases, and vice versa. The change in resistance occurs which is proportional to temperature. At the beginning of its development, RTD was in the form of a wire-wound (RTD-C), but over time it began to be replaced by a resistance temperature detector film (RTD-F) [9-10]. The RTD-C sensor has the disadvantages of a low measurement range. In contrast to the RTD-F sensor which has a faster thermal response and a better sensor sensitivity level [11].

There are several materials commonly used as materials for making RTDs. Usually made of pure metal elements such as platinum (Pt) [12], Nickel (Ni) [13], and copper (Cu) [14]. However, in this study, Cu and Ni were synthesized. Basically, Cu has the potential to be a temperature sensor [15], it's just that Cu is still less sensitive to temperature changes. This is because the resistivity possessed by Cu tends to be very low [16] as well as the nature of Cu which is easily oxidized. Basically, Cu sensitivity can be increased by synthesizing it with Ni which has a higher resistivity value, namely Ni to form a thin layer structure of Cu/Ni. Another advantage of Ni is that it has a better adhesion force compared to Pt, making it easier for film deposition [17]. Cu/Ni material also has a relatively high-temperature coefficient value [18]. So it is very suitable to be applied as a low-temperature sensor. Based on these advantages, the reasons for choosing Cu and Ni in this study. The synthesis method used in this research is electroplating because it is more economical, fast, with a process that is easy to control [18]. Electroplating is carried out with temperature variations aided by parallel magnetic fields. The role of parallel magnetic fields is to form a more regular and uniform distribution of particles [19]. The use of magnetic fields also plays a role in increasing the mass deposition of particles [20]. This results in a more homogeneous Ni layer structure. Then temperature plays an important role in reducing the viscosity of the solution so as to facilitate the rate of ion deposition [21]. The combination of these two parameters has the potential to improve the crystal arrangement to become homogeneous so as to increase the sensitivity of the sensor.

Based on previous research that carried out Cu/Ni synthesis assisted by perpendicular magnetic fields, it produces a rough layer structure. So as to produce a low sensor sensitivity, namely $V = -7 \times 10^{-7}\ T^2 + 0{,}0003\ T + 0{,}4746$ with a determination index of 0.99 [22]. Therefore it is important to study the effect of solution temperature aided by parallel magnetic fields on the voltage range and sensitivity of the sensor.

2. MATERIALS & EXPERIMENTAL PROCEDURES

This research is experimental research. The flow of this research follows the procedure shown in Figure 1.

The material needed in this research is Liquid Nitrogen (LN_2). Meanwhile, the tools used are a computer, a TCA-BTA thermocouple, transducer, wire, voltage sensor, LN_2 container, 4-WCB, mini quest lab, and Cu/Ni sensors. The specifications of the Cu/Ni sensor are 7.61 cm wide, 0.5 mm thick Cu plate, the thickness of the Ni layer structure varies from (59-133) μm with a square wave sample shape. Low-temperature sensor testing in this study uses LN_2 as a low temperature. Because the temperature of LN_2 is a cryogenic temperature of -196°C [23]. The test is carried out very carefully, by inserting the sensor slowly in order to ensure that the reading of the data is stable without missing a temperature range. The test media used

was an LNcontainer$_2$ with a volume ofLN_2 10 liters of. Even though it contains LN_2 , the temperature inside the container varies with the difference in the distance between the sensor and the medium. The bottom temperature of the LNcontainer$_2$ is lower than the temperature at the mouth of the container. Cu/Ni sensor testing is carried out simultaneously with the TCA-BTA thermocouple sensor. Cu/Ni sensor output data with thermocouples is different because Cu/Ni sensors have output data in the form of a voltage (V) instead of temperature (T). In order to avoid contributing to the output voltage from the cable due to leakage of the voltage generated by the sensor which results in measurement errors, the sensor is connected to a 4-WCB circuit (Four Wire Configuration Bridge) [24]. The Cu/Ni sensor output voltage range used in this study is in the temperature range of 20°C to -196°C. The output data of the two sensors is observed in the form of graphical visualization and tables in the Logger Pro software. The output data is analyzed for sensor sensitivity and voltage range. Analyze sensor sensitivity based on the voltage-temperature (curve V-T), while analyzing the sensor voltage range using the maximum and minimum voltage output of the sensor.

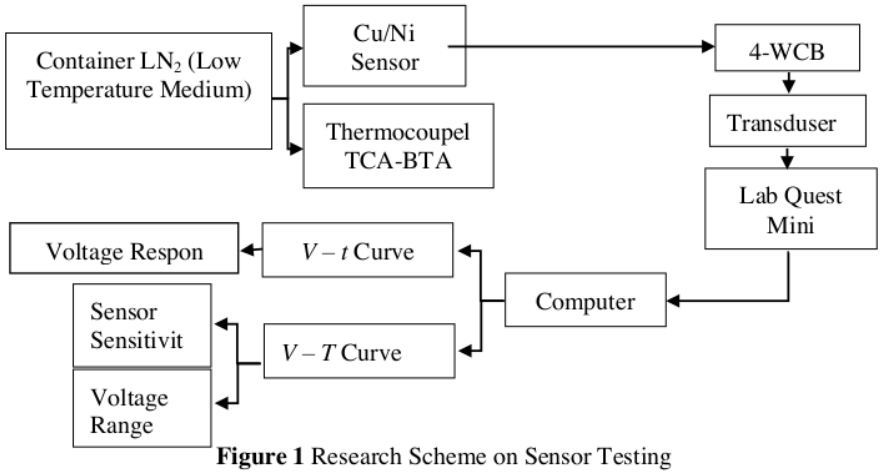

Figure 1 Research Scheme on Sensor Testing

Sensor sensitivity was analyzed using the second-order polynomial equation [25]. The most sensitive sensor is determined based on the value of b largest [26]. The relationship between voltage (V) and temperature (T) has a relationship which is described in the following equation [27].

$$V = aT^2 + bT + c \quad (1)$$

Where, V is voltage (V), T is temperature (°C), a is curvature, b is slope, and c is intercept.

3. RESULTS AND DISCUSSION

Figure 2 is the response of the Cu/Ni low-temperature sensor voltage to LNtemperature$_2$ in the *container*. The difference in output voltage response indicates that the deposition temperature of the material affects the sensor's voltage-time (V-t) curve. The horizontal axis of the image informs that each sensor deposited at a different solution temperature has a different response time to reach the maximum temperature of LN_2 [28] before returning to its original temperature. The difference in response time is caused by the microstructure of the films and the experimental parameters used in their manufacture [29]. The process of measuring sensor resistance is carried out by simultaneously inserting a thermocouple low-temperature sensor as a calibration tool. Calibration is carried out to minimize the uncertainty of data acquisition by sensors so that the resistance relationship of each sensor to temperature is obtained [30]. The RTD Cu/Ni sensor calibration process is carried out in an LNcontainer$_2$ starting at a

temperature of 20°C - 196°C and then maintains it for a while in the LNcontainer$_2$ until the sensor voltage decreases to its maximum state before the sensor is lifted back up again at 20°C During the process of testing the sensor capability, the voltage-time (*V-t*) curve at a certain time appears to decrease when the temperature increases and the voltage curve rises when the temperature in the container decreases so that the voltage curve appears to be curved or offset. Such events often occur because the RTD detects the danger of thermal disturbance with high efficiency at room temperature to the initial temperature of the test [31]. The thermal disturbance in question is the difference in thermal capacitance and thermal conductivity that appears between measurement instruments. However, in general, the Cu/Ni sensor shows a linear and stable curve with thermocouple sensor output data, especially at low temperatures. The shape of the curve (*V-t*) in the sensor resistance test in this study also still has ripples in the reading of the data. This ripple is thought to arise as a result of fluctuations in the sensor that occurs for a long time due to the entry of CO_2 into the container, as well as the appearance of electrical disturbances that arise from the entire circuit [32]. Another cause of the presence of ripples in the sensor output voltage is due to the microstructure of the Cu/Ni sensor layer. A layer structure with a uniform and regular crystal size will produce a relatively more stable output voltage because electric current can easily flow through the layer structure. Unlike the layer structure which has non-uniform crystal size and an irregular crystal arrangement, it will inhibit the current through the layer structure so that the output voltage becomes unstable.

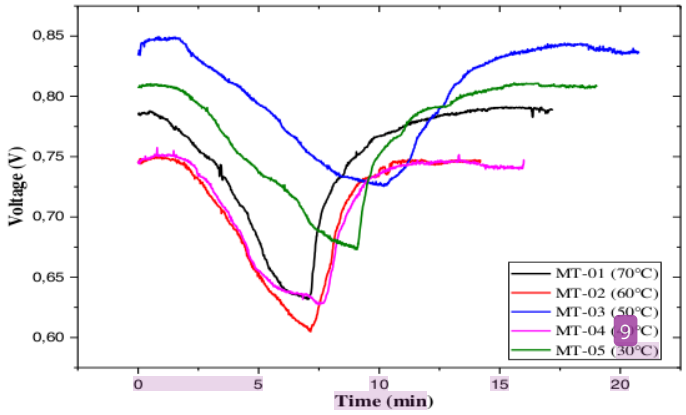

Figure 2 Cu/Ni output voltage

During the sensor resistance testing process, there is an interesting point where the resistance of the Cu/Ni sensor is much better than the thermocouple sensor. One of them is clearly visible on the RTD Cu/Ni sensor deposited at 60°C. This event occurs because the thermocouple sensor freezes so that no current flows [33]. The difference in the sensing limit of the thermocouple and Cu/Ni sensor measurements can be seen in Figure 3.

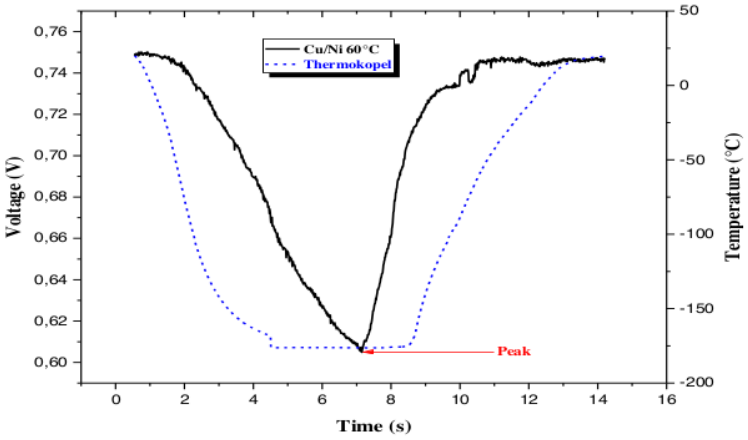

Figure 3. Output Voltage Cu / Ni sensor and Thermocouple Sensor

Voltage Range. Figure 3 is a visualization of the voltage range of each Cu/Ni sensor deposition temperature variation. The voltage range of each sensor determines the level of accuracy and precision of temperature measurements by each sensor [34].

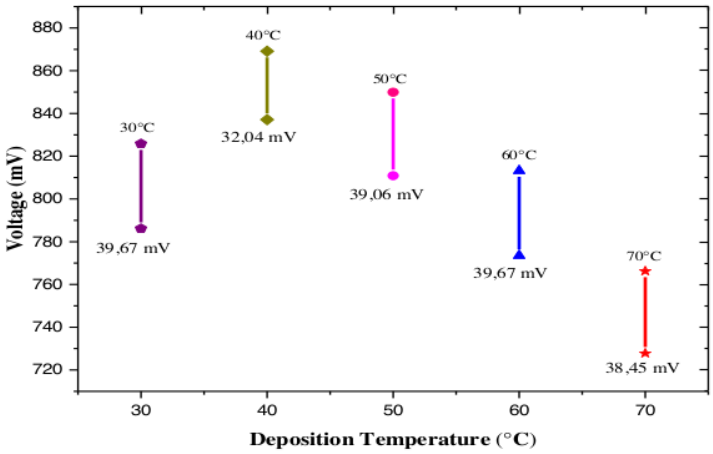

Figure 4. Voltage Range Sensor Cu/Ni deposited at temperature variations

Each Cu/Ni sensor output voltage range that was deposited at various temperature solutions looked different, from 32.04 mV to 39.67 mV. The highest voltage range for the Cu/Ni sensor is 39.67 mV with a deposition temperature of 30°C and 60°C. Then 38.45 mV for sensors deposited at 70°C while sensors deposited at 40°C have the smallest voltage range, namely 32.04 mV.

Sensor Sensitivity. The level of sensor sensitivity is determined by the accuracy of the sensor output voltage change in response to temperature changes in the LNcontainer$_2$ [27]. Data collection was set at 10 samples per second with a very slow data collection rate of 0.2 cm/s. The sensor is lowered slowly into the LNcontainer$_2$ in order to avoid gradient effects [28]. The overall output voltage of the Cu/Ni sensor tends to form a polynomial. The sensor output voltage displayed on the curve (*V-T*) is a temperature range of -170°C to 0°C. The range of -170°C was chosen because it conforms to the accurate measuring limit of the thermocouple.

The relationship of voltage to temperature and the sensitivity level of the Cu/Ni sensor can be seen in Figure 5.

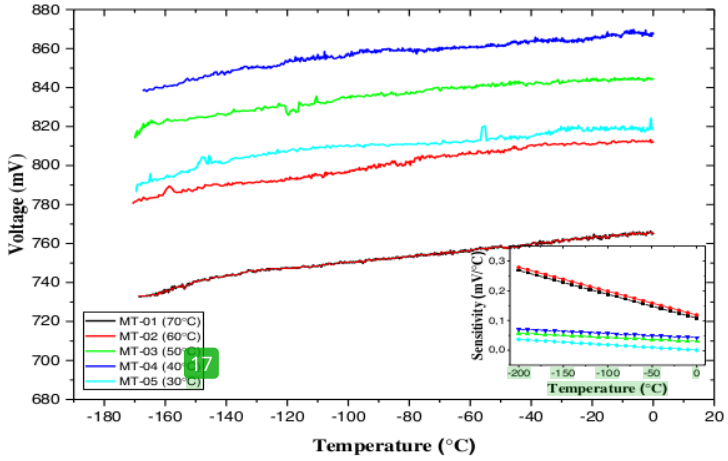

Figure 5 Cu/Ni Sensor Voltage Responds to LN_2 Temperature

Based on the test results, the entire sample shows a strong tendency to decrease stress following linear regression to temperature [35]. This relationship that tends to be linear is caused by the scattering of electrons by lattice vibrations (phonons) because at high temperatures the phonons will vibrate with higher amplitude than low temperatures [36]. This data distribution pattern is a simple form that describes the relationship between temperature and resistance in RTDs. The results of *fitting* Cu/Ni sensor output voltage data to LNtemperature$_2$ can be seen in Table 1.

Table 1 Output Fitting Output Sensor Cu/Ni Sensor

Depotition Temperature (°C)	$V = aT^2+b$	S_b	R^2
70	-0,0004 T^2 + 0,108	0,003	0,99
60	-0,0004 T^2 + 0,118	0,004	0,98
50	-0,0007 T^2 + 0,029	0,003	0,99
40	-0,0007 T^2 + 0,042	0,003	0,97
30	-0,0009 T^2 + 0,0004	0,007	0,96

Based on Table 2, it informs that the results fitting of the regression data(V -T) with a and b. The entire sample shows different levels of sensitivity and data stability when tested to measure the temperature of LN_2 as a low-temperature sensor. However, based on the results of overall observations, it can be seen that Cu/Ni sensors deposited using high temperature are more sensitive than those using room temperature. The highest sensor sensitivity is owned by Cu/Ni sensors that are deposited with a temperature of 60°C, namely (0.118 ± 0.004) mV/°C, and the lowest sensitivity is owned by Cu/Ni sensors that are deposited at 30°C with a sensitivity level (0,0004 ± 0.007) mV/°C. While the stability of the sensor output data are best owned by a sensor Cu/Ni was deposited at 50°C and 70°C with an index value of determination R^2 = 0.99. While the sensor with the lowest data stability owned by sensors Cu/Ni was deposited at 30°C with an index value of determination R^2 = 0.96. Apart from seeing the value b biggest, determining the sensitivity level of the Cu/Ni sensor can also be seen from the slope of the curve shape as shown in Figure 5 because the sensor sensitivity is obtained from the slope of the resistance measurement curve to temperature [37]. So that the

tilted the resulting curve shows the higher the sensitivity level of the sensor. The high sensitivity of the test is also associated with the lack of defects in the layer structure and sufficient thickness, so it is very good at reducing electron scattering [38-39].

4. CONCLUSIONS

Cu/Ni sensors with wave square lithography are made using the electroplating method at various temperature solutions with the help of parallel magnetic fields. The results showed sensor Cu/Ni was deposited at a 60°C sensor is the most sensitive and most stable solution (0.118 ± 0.004) mV/°C with R^2= 0.98. Meanwhile, the highest Cu/Ni sensor voltage range is 39.67 mV with a deposition temperature of 30°C and 60°C, and the smallest voltage range is 32.04 mV as a result of deposition at 40°C. As a result, the Cu/Ni sensor that is deposited at 60°C with the RTD-F type can be a reference as a low-temperature sensor in various fields because it is very sensitive to reach temperatures of -196°C and has the highest voltage range.

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